

Sensors and Actuators 81 (2000) 23-26



www.elsevier.nl/locate/sna

Effects of aging on the electrical resistivity of $La_{1-x}B_xCoO_3$ perovskites (B = Sr, Ca, Ba; $0.20 \le x \le 0.30$)

J. Mira^{a,*}, J. Rivas^a, M.P. Breijo^b, M.A. Señarís Rodríguez^b, R.D. Sánchez^c

^a Departamento de Física Aplicada, Universidade de Santiago de Compostela, E-15706 Santiago de Compostela, Spain
^b Departamento de Química Fundamental e Industrial, Universidade da Coruña, E-15071 A Coruña, Spain
^c Departamento de Física, Universidad de Buenos Aires, 1428 Buenos Aires, Argentina

Abstract

A study of the reliability of the title compounds as a basis for magnetoresistive sensors is presented. For this purpose we have carried out long-term systematic studies of the evolution of the resistive and magnetic properties of samples synthesized by both ceramic and wet chemical routes, allowing them to age during several months. It is observed that, although the magnetic properties remain unaltered, their resistivity does change appreciably. With time, samples that are initially metallic over all the measured temperature range (T < 300 K), change to semiconductor-like behaviour at low temperatures and above their ferromagnetic to paramagnetic phase transition temperature, giving rise to a 'reentrant semiconducting behaviour' with associated high electrical noise, relaxation effects of the resistivity and even diodic behaviour. © 2000 Elsevier Science S.A. All rights reserved.

Keywords: Aging effects; Perovskites; Oxygen stoichiometry; Magnetoresistance

1. Introduction

The topic of magnetic field sensing has experienced a notable activity in the last decade, since the discovery by Baibich et al. of high magnetoresistance in antiferromagnetically coupled multilayers [1]. Later on, the finding of a huge magnetoresistance (or 'colossal magnetoresistance', CMR) in Mn-based perovskites LaMnO₃ [2,3] attracted many physicists on the phenomenon and on other related materials with other 3d transition metals than Mn which had been already studied in the fifties [4,5].

Among perovskites $LaCoO_3$ has an unique behaviour which lies on the changing nature of the Co³⁺ spin state [6]. Upon Sr doping the material starts to segregate into hole-rich metallic ferromagnetic clusters and a hole-poor LaCoO₃-like matrix that mediates the interactions among the clusters [7]. At x = 0.20 a magnetic percolation threshold is reached and the system shows bulk ferromagnetism below $T_c \sim 240$ K [8]. They also show negative MR [9], but it is only as high as $\approx 8\%$ for La_{0.7}Sr_{0.3}CoO₃ [10]; however, the MR effect is linear with the applied field for a wide field range and MR does not saturate at least below 70 kOe [11]. This has prompted proposals for the application of $La_{0.7}Sr_{0.3}CoO_3$ as a low temperature linear magnetic field sensor [11]. Here we focus on the reliability of the title compounds for their use as a basis of magnetic field sensors.

2. Results

Polycrystalline single-phase samples were prepared by different routes leading to diverse particle sizes. In Fig. 1 we show the resistivity vs. temperature curves of a largegrain-size $La_{0.80}Sr_{0.20}CoO_3$ sample, measured in the asprepared material (A), seven months later (B) and ten months later (C). Initially the compound is metallic, and presents the typical change of slope below T_c due to magnon scattering of the carriers in the magnetically ordered phase [12]. But, with time the metallic behaviour is lost at low temperatures and above T_c . Magnetization data taken in the same period do not show significative changes. Also, from a crystallographic point of view the sample did not experience any structural modification (as shown by its X-ray diffraction pattern).

This evolution is faster in samples of smaller grain size, as seen in Fig. 2, for $La_{0.70}Sr_{0.30}CoO_3$. In this case a

^{*} Corresponding author. Fax: +34-981-520676; E-mail: fajmirap@usc.es

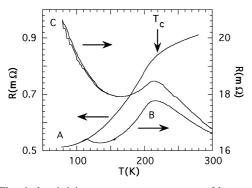


Fig. 1. Electrical resistivity versus temperature curve of large-grain-size $La_{0.8}Sr_{0.2}CoO_3$ measured for the as-prepared sample (A), seven months later (B) and ten months later (C). Horizontal arrows mark the corresponding scales. Note the presence of a change of conduction regime at T_c .

metallic regime is found for the as prepared sample, but after five months (curve D) metallic behaviour is lost above T_c ; then there is a transition to a metallic regime and again an upturn to semiconductive behaviour at low temperatures. For some compositions, a similar tendency is observed in the as-prepared samples, with a clear semiconductor behaviour above T_c , composing what we have named 'reentrant semiconducting behaviour' (RSB). La_{0.80}Ba_{0.20}CoO₃ and La_{0.70}Ca_{0.30}CoO₃ belong to this group. In such a case the final evolution is towards a pure semiconductive behaviour over the whole temperature range, as seen in Fig. 3 for La_{0.80}Ba_{0.20}CoO₃; A corresponds to the initial measurement, and B, C and D to runs taken after two, four and six months respectively. We have measured the magnetoresistance in steps C and D at the temperatures where differences between R(H=0) and R(H = 5 kOe) are a maximum. In Fig. 4a we show the magnetoresistance for the C stage; a strong electrical noise is seen. Once the RSB is lost, i.e., the intermediate metallic regime is lost (case D) the MR was measured again and it was seen that the electrical noise is considerably reduced (Fig. 4b). Materials that show RSB also display other unusual properties besides high electrical noise. One of

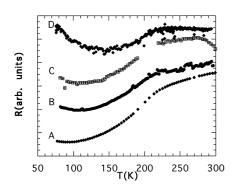


Fig. 2. Electrical resistivity versus temperature curve of small-grain-size $La_{0.7}Sr_{0.3}CoO_3$ at several stages, going from the as-obtained sample (A) to a five-month-old one (D).

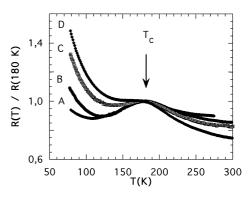


Fig. 3. Normalized electrical resistivity versus temperature curve of $La_{0.8}Ba_{0.2}CoO_3$ at several stages, taken every two months, from the as-prepared stage (A) to the six-month-old one (D). The ferromagnetic transition temperature (T_c) for this sample is marked with an arrow.

them is a different value of resistivity depending on the sign of the applied measuring electrical intensity. The change of resistivity when inverting the sign of the electrical intensity is not immediate, but presents a time dependent relaxation. In $La_{0.80}Ba_{0.20}CoO_3$ for example, to recover the resistivity measured before the current switch a time of about 600 s is needed. It is worth noting that interface effects between sample and electrical contacts (used for the resistivity measurements) must be discarded. To ensure this point, the silver paint contacts used initially were renewed after detecting changes in resistivity and, in

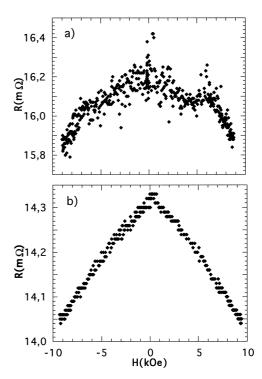


Fig. 4. Magnetoresistance of the La_{0.8}Ba_{0.2}CoO₃ sample, when it presented RSB (a) and after becoming completely semiconductive (b). In both cases MR is measured where R(H) vs. *T* curves at H = 0 and H = 5 kOe display the maximum difference.

some cases they were replaced by four new contacts, pressing metallic indium or sputtering gold onto the sample. In all the cases new thermal treatments followed by slow cooling in air to room temperature made the samples return to the initial conditions.

3. Discussion

The main requirement for a practical magnetic field sensor is reproducibility. In this work a long term storage test evidences important variations in the electrical properties of Co-based perovskites. It must be noted the recovering of initial properties of the material after new thermal treatments at high temperature followed by a slow-cooling to room temperature so as to ensure the right oxygen stoichiometry. This suggests that oxygen content plays a crucial role on the electrical properties of these cobaltites. This dependence has already been detected in electrodes made with the parent compound $La_{0.5}Sr_{0.5}CoO_3$ [13], for which a slow cooling in an oxygen deficient atmosphere led to pure semiconducting phases. Here in addition, we see RSB in some stages of the samples. This peculiarity had already been reported by Señarís Rodríguez and Goodenough in Sr-doped cobaltites [8] and attributed to the changing spin state of the LaCoO₃-like hole-poor phase segregated in it. The small energy gap between low spin $(t^6e^0, S=0)$ and high-spin $(t^4e^2, S=2)$ configurations (in the order of 0.03 eV) allows a thermally activated increase of the population of the latter one, taking place gradually in the temperature range 35–100 K, until a 50:50 ratio is achieved. This rate is maintained up to 300 K; in between a dynamic fluctuating equilibrium between high-spin and low-spin Co^{3+} ions is established [6]. Just below T_c the ferromagnetic metallic regions percolate magnetically, but they are embedded in the LaCoO₃-like matrix, that contains a certain proportion of high-spin Co³⁺ ions, i.e., with carriers in the conducting e-bands, enabling conduction. But below 100 K the decreasing population of high-spin ions reestablishes a semiconducting dependence. Oxygen deficiencies would have the effect of decreasing hole carriers (two holes lost per oxygen vacancy) and therefore would decrease conductivity. Oxygen losses are favoured by smaller particle sizes. It is reasonable to think that a higher surface/volume ratio for smaller particle sizes enables a faster reducing process.

In summary, we conclude that possible users of Cobased perovskites as magnetic field sensors or other applications should be aware of the variable conduction character of these materials, tending to reentrant semiconducting behaviours that, among other features, present a very noisy magnetoresistive effect. Probably a protective coating should be provided for the use of these perovskites to guarantee long-term storage stability.

Acknowledgements

We wish to acknowledge Spanish DGICYT for financial support under project PB94-1528.

References

- M.N. Baibich et al., Giant magnetoresistance of (001)Fe/(001)Cr magnetic superlattices, Phys. Rev. Lett. 61 (1988) 2472–2475.
- [2] R. von Helmolt, J. Wecker, B. Holzapfel, L. Schultz, K. Samwer, Giant negative magnetoresistance in perovskite La_{2/3}Ba_{1/3}MnO_x ferromagnetic films, Phys. Rev. Lett. 71 (1993) 2331–2333.
- [3] S. Jin, T.H. Tiefel, M. McCormack, R.R. Fastnacht, R. Ramesh, L.H. Chen, Thousandfold change in resistivity in magnetoresistive La-Ca-Mn-O films, Science 264 (1994) 413-415.
- [4] J.B. Goodenough, Theory of the role of covalency in the perovskitetype manganites [La, M(II)]MnO₃, Phys. Rev. 100 (1955) 564–573.
- [5] J.B. Goodenough, Magnetism and the chemical bond, Wiley, New York, 1963, pp. 221–238 and references therein.
- [6] M.A. Señarís Rodríguez, J.B. Goodenough, LaCoO₃ revisited, J. Solid State Chem. 116 (1995) 224–231.
- [7] J. Mira, J. Rivas, R.D. Sánchez, M.A. Señarís Rodríguez, D. Fiorani, D. Rinaldi, R. Caciuffo, AC magnetic susceptibility measurements in La_{1−}, Sr_yCoO₃ (x ≤ 0.30), J. Appl. Phys. 81 (1997) 5753–5755.
- [8] M.A. Señarís Rodríguez, J.B. Goodenough, Magnetic and transport properties of the system La_{1-x}Sr_xCoO₃ (0 < x ≤ 0.50), J. Solid State Chem. 118 (1995) 323–336.
- [9] V. Golovanov, L. Mihaly, A.R. Moodenbaugh, Magnetoresistance in $La_{1-x}Sr_xCoO_3$ for $0.05 \le x \le 0.25$, Phys. Rev. B 53 (1996) 8207–8210.
- [10] R. Mahendiran, A.K. Raychaudhuri, Magnetoresistance of the spinstate compound La_{1-x}Sr_xCoO₃, Phys. Rev. B 54 (1996) 16044– 16052.
- [11] R. Mahendiran, A.K. Raychaudhuri, A. Chainani, D.D. Sarma, Low temperature linear magnetic field sensor based on magnetoresistance of the perovskite oxide La–Sr–Co–O, Rev. Sci. Instrum. 66 (1995) 3012–3071.
- [12] S.V. Vonsovskii, Magnetism, Ch. 25, Vol. 2, Wiley, 1950.
- [13] S. Madhukar, S. Aggarwal, A.M. Dhote, R. Ramesh, A. Krishnan, D. Keeble, E. Poindexter, Effect of oxygen stoichiometry on the electrical properties of La_{0.5}Sr_{0.5}CoO₃ electrodes, J. Appl. Phys. 81 (1995) 3543–3547.

Biographies

J. Mira was born in Baio, Spain, in 1968. He received the B.S. and M.S. degrees in physics from the University of Santiago de Compostela in 1991 and 1992, respectively, and the PhD and European PhD degrees in physics from the same university in 1995. He is currently Assistant Professor at the Faculty of Physics at the University of Santiago de Compostela. His topic of research involves the study of magnetic materials and magnetism in solids. He published more than 40 scientific papers.

J. Rivas was born in Lugo, Spain, in 1947. He received the PhD degree in physics from the University of Valladolid, Spain, in 1973. He has been a research worker at the Max-Planck-Institut, Stuttgart, Germany (1974– 1975), and Assistant Professor at the Universities of Valladolid and Murcia, Spain (1975–1981). Since 1981, he has been Professor of Physics at the University of Santiago de Compostela. His topic of research involves the study of magnetic materials, on which he has published more than 100 scientific papers. *M.P. Breijo* was born in Santander, Spain, in 1970. She obtained her B.S. degree in Physics from the University of Santander in 1994. She is currently working towards the PhD degree on electrical and magnetic properties of perovskite materials, at the Faculty of Chemistry of the University of A Coruña, Spain.

M.A. Señarís Rodríguez was born in Santiago de Compostela, Spain, in 1965. She obtained her B.S. and PhD degrees in Chemistry from the Universities of Santiago de Compostela (1988) and Complutense de Madrid (1992), respectively. She was a Fullbright scholar at the University of Texas at Austin (1993–1994). She is currently Professor of inorganic chemistry at the University of A Coruña. Her research includes the synthesis of mixed oxides of low particle size and the study of electrical and magnetic properties of Co-based perovskites.

R.D. Sánchez was born in Córdoba, Argentine, in 1962. He obtained his B.S. degree in Chemistry from the University of Córdoba in 1985, and the PhD degree in Physics from the University of Cuyo - Instituto Balseiro, Bariloche (Argentine) in 1992. His topics of research have been related with EPR studies in superconducting materials and magnetic and electric properties of perovskite materials. He is now a staff research member at the Centro Atómico Bariloche - Instituto Balseiro, Bariloche (Argentine).